

Vladimir Evstigneev

List of Publications by Year in descending order

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| # | ARTICLE | IF | CITATIONS |
|---|---|-----|-----------|
| 1 | Arsenic Doping Upon the Deposition of CdTe Layers from Dimethylcadmium and Diisopropyltellurium. Semiconductors, 2021, 55, 7-13. | 0.5 | 1 |
| 2 | Growth of Arsenic-Doped Hg _{1-x} Cd _x Te (x ~ 0.4) Epilayers by Metalorganic Chemical Vapor Deposition. Inorganic Materials, 2019, 55, 984-988. | 0.8 | 2 |
| 3 | Electrophysical Properties of p-Type Undoped and Arsenic-Doped Hg _{1-x} Cd _x Te Epitaxial Layers with x ~ 0.4 Grown by the MOCVD Method. Semiconductors, 2018, 52, 702-707. | 0.5 | 4 |
| 4 | Growth of arsenic-doped cadmium telluride epilayers by metalorganic chemical vapor deposition. Inorganic Materials, 2016, 52, 1210-1214. | 0.8 | 5 |